

MPFS100R12DBF

1200V 100A IGBT Module

Electrical Features

- Trench/Fieldstop IGBT
- V_{CEsat} with positive Temperature Coefficient
- Low V_{CEsat}

Typical Applications

- Auxiliary inverters
- Motor drives
- Servo drives

Mechanical Features

- High power density
- Integrated NTC temperature sensor
- Copper base plate
- Solder contact technology
- Standard housing



IGBT, Inverter

Maximu	m Rated Values						
Symbol	Item	Conditions			Rating		Unit
IGBT							
V _{CES}	Collector-emitter voltage	T _{vj} =25°C			1200		V
V _{GES}	Gate-emitter voltage	-			±20		V
$I_{\rm C}$	Collector current,DC	T _C =100°C,T _{vj} =175°	°C		100		A
I _{CRM}	Repetitive peak collector current	t _p =1ms			200		A
P _{tot}	Total power dissipation	T _C =25°C,T _{vj} =175°C	C		34	12	W
Characte	eristics Values						1
Symbol	Item	Conditions			Values	Unit	
IGBT				Min.	Тур.	Max.	
Ices	Collector-emitter cut-off current	V _{CE} =1200V,V _{GE} =0V,T _{vj} =25°C		-	-	1	mA
I _{GES}	Gate leakage current	V _{CE} =0V,V _{GE} =20V,T _{vj} =25°C		-	-	100	nA
V _{GE(th)}	Gate-emitter threshold voltage	I _C =3.8mA,V _{CE} =V _{GE} ,T _{vj} =25°C		5.2	5.86	6.2	V
	Collector-emitter saturation voltage	I _C =100A	T _{vj} =25°C	-	1.81	-	
V_{CEsat}		$V_{GE}=15V$	T _{vj} =125°C	-	-	-	V
			T _{vj} =150°C	-	-	-	
Cies	Input capacitance	$-V_{CE}=25V,V_{GE}=0V$ $f=1MHz,T_{vj}=25^{\circ}C$		-	7.07	-	
Coes	Output capacitance			-	0.46	-	nF
Cres	Reverse transfer capacitance			-	0.24	-	-
Q _G	Gate charge	V _{CC} =600V, I _C =100A V _{GE} =-15+15V,T _{Vi} =25°C		-	0.64	-	μС
Rg	Internal gate resistance	T_{vj} =25°C			1.8	-	Ω

			T _{vj} =25°C	_	200	_	
$t_{d(on)}$	Turn-on delay time		$T_{vj} = 125^{\circ}C$	_	-	_	_
ed(OII)	Turn on delay time		$T_{vj} = 150$ °C	-	_	_	
			T_{vj} =25°C	_	246	_	-
$t_{\rm r}$	Rise time		$T_{vj}=125$ °C	_	-	_	-
ti Rise time	1400 4440		$T_{vj}=150$ °C	_	_	_	
			T_{vj} =25°C	_	262	_	ns -
$t_{\rm d(off)}$	Turn-off delay time	$V_{CC}=600V$	$T_{vj}=125$ °C	_	_	_	
-4(011)	and the meany many	$I_C=100A$	$T_{vj}=150$ °C	_	_	_	
		$V_{GE}=\pm 15V$	$T_{vj}=25^{\circ}C$	-	234	_	
t_{f}	Fall time	$R_{G(on)}=1.6\Omega$	$T_{vj}=125$ °C	_	_	_	_
		$R_{G(off)}=1.6\Omega$	$T_{\rm vj}=150^{\circ}{\rm C}$	_	-	_	-
			T_{vi} =25°C	-	2.23	_	
Eon	Turn-on energy (per pulse)		$T_{vj}=125$ °C	-	-	-	
			$T_{vj}=150$ °C	-	-	-	1 .
			T_{vi} =25°C	_	6.9	-	mJ
E_{off}	Turn-off energy (per pulse)		$T_{vj}=125$ °C	-	-	-	
			T _{vj} =150°C	-	-	-	
00.1	GI	V _{CC} =600VV _{GE} <15VT _{vi} =25°C			1037		1.
SC data	Short-circuit current	$V_{\text{CES}} \leq 1200 \text{V}, t_{\text{P}} \leq 1200 \text{V}$	V _{CES} ≤1200V,t _P ≤10μs			-	A
R _{thJC}	Thermal resistance, junction to case	Per IGBT	-	-	0.44	K/W	
R_{thCH}	Thermalresistance, case to heatsink	Per IGBT λgrease=1W/(m·K)			0.13	-	K/W
Tvjop	Temperature under switching conditions		-40			150	°C
Diode,	Inverter				1		1
Maximu	m Rated Values						
Symbol	Item	(Conditions Rating				Unit
V_{RRM}	Repetitive peak reverse voltage	T _{vj} =25°C	T_{vi} =25°C			00	V
I_{F}	Forward current,DC					00	A
I_{FRM}	Repetitive peak forward current	t _p =1ms			20	00	A
I ² t	I ² t-value	$V_R=0V,t_p=10ms,$	$V_R = 0V, t_p = 10 \text{ms}, T_{vj} = 150 ^{\circ}\text{C}$			00	A ² s
Characte	eristic Values	•					1
		T 100 A	T _{vj} =25°C	-	1.83	-	
V_{F}	Continuous forward voltage	$I_F=100A$	T _{vj} =125°C	-	-	-	V
		$V_{GE}=0V$	T _{vj} =150°C	-	-	-	
			T _{vj} =25°C	-	145	-	
I_{RM}	Peak reverse recovery current		T _{vj} =125°C	-	-	-	A
			T _{vj} =150°C	-	-	-	
	Reverse recovery time	$V_R=600V$	T _{vj} =25°C	-	136	-	
t_{rr}		$I_F=100A$	T _{vj} =125°C	-	-	-	ns
		$V_{GE}=-15V$	T _{vj} =150°C	-	-	-	
	<u> </u>		_ Tvj 150 C				Т
			T_{vj} =25°C	-	8.9	-	
Q_{r}	Recovered charge			-	8.9	-	μС

Erec			T _{vj} =25°C	ı	6.07	-	
	Reverse recovery energy		$T_{vj}=125$ °C	ı	1	-	mJ
			$T_{vj}=150$ °C	-	-	-	
R _{thJC}	Thermal resistance, junction to case	per diode		-	-	0.5	K/W
R _{thCH}	Thermal resistance, case to heatsink	per diode, λ _{grease} =1 W/(m • K)		-	0.225	-	K/W
$T_{ m vjop}$	Temperature under switching			-40		150	°C
	conditions			-40		130	

Note:

IGBT electrical characteristics according to IEC 60747 - 9

Diode electrical characteristics according to IEC 60747 – 2

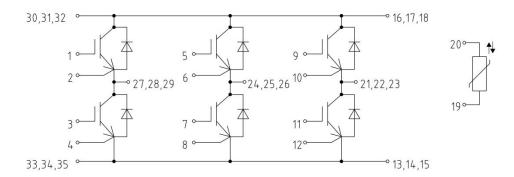
NTC Thermistor Characteristics

Symbol	Item	Conditions		Unit		
		Conditions	Min.	Тур.	Max.	
R ₂₅	Rated resistance	T _C =25°C	-	5	-	kΩ
$\Delta R/R$	Deviation of resistance	$T_{\rm C}=100^{\circ}{\rm C}, R_{100}=493\Omega$	-5	-	5	%
P ₂₅	Power dissipation	T _C =25°C	-	-	20	mW
B _{25/50}	B-constant	$R_2=R_{25}\exp[B_{25/50}(1/T_2-1/(298.15K))]$	-	3375	_	
B _{25/80}	B-constant	$R_2=R_{25}\exp[B_{25/80}(1/T_2-1/(298.15K))]$	-	3411	-	K
B _{25/100}	B-constant	$R_2=R_{25}\exp[B_{25/100}(1/T_2-1/(298.15K))]$	-	3433	-	

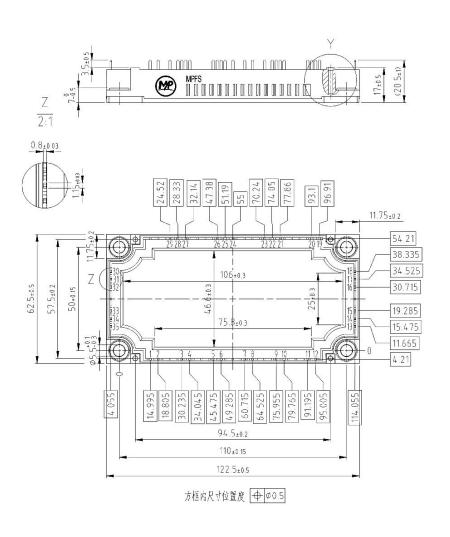
Module

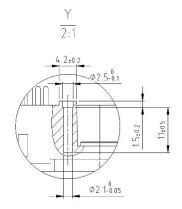
Symbol	Item	Conditions	Rating			Unit	
V _{ISOL}	Isolation voltage	Terminals to baseplate, RMS,f=50Hz,t=1min	2500			V	
T _{vjmax}	Maximum junction temperature	-	175			°C	
T_{vjop}	Operating junction temperature	Continuous operationg(underswitching)	-40~150			°C	
T_{stg}	Storage temperature	-	-40~125		5	°C	
Cymah al	Item	Conditions	Values			Unit	
Symbol		Conditions		Тур.	Max.		
M	Mountingtorqueformodulmoun ting	-	3	-	6	Nm	
ds	Creepage distance	Terminal to terminal	-	-	-	mm	
		Terminal to base plate	-	10	-		
da	Clearance	Terminal to terminal	-	-	-	400.400	
		Terminal to base plate	-	7.5	-	mm	
m	Weight	-	-	- 290 -		g	

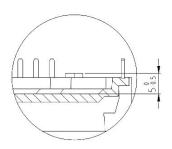
Cricuit Diagram



Package Outlines







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